NSN 5961-01-275-0811

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-275-0811 **Inclosure Material:** Metal **Overall Length:** 1.646 inches **Function For Which Designed:** Rectifier **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.650 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 nonrepetitive peak off-state voltage and 200.0 nonrepetitive peak reverse voltage and 200.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 25.00 amperes forward current, total rms horsepower metric and 200.00 amperes forward current, total rms torr **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator: Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No **Fiig:**

A110a0